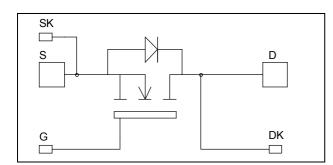


Single Switch MOSFET Power Module

$$\begin{split} V_{DSS} &= 200V \\ R_{DSon} &= 3m\Omega \text{ typ } @ \text{ Tj} = 25^{\circ}\text{C} \\ I_D &= 580\text{A} @ \text{ Tc} = 25^{\circ}\text{C} \end{split}$$



Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS 7® FREDFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic reverse diode
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration
- AlN substrate for improved thermal performance



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit		
$V_{ m DSS}$	Drain - Source Breakdown Voltage		200	V	
Ţ	Continuous Drain Current	$T_c = 25$ °C	580		
I_D	Continuous Drain Current	$T_c = 80$ °C	434	A	
I_{DM}	Pulsed Drain current		2320		
V_{GS}	Gate - Source Voltage		±30	V	
R _{DSon}	Drain - Source ON Resistance		3.6	mΩ	
P_D	Maximum Power Dissipation $T_c = 25^{\circ}C$		2270	W	
I_{AR}	Avalanche current (repetitive and non repetitive)		100	A	
E_{AR}	Repetitive Avalanche Energy		50	mJ	
E_{AS}	Single Pulse Avalanche Energy		3000	1113	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
T	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 200V$ $T_j = 25^{\circ}C$			500	μА
$I_{ m DSS}$		$V_{GS} = 0V, V_{DS} = 160V$ $T_j = 125^{\circ}C$			3000	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 290A$		3	3.6	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 15$ mA	3		5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±400	nA

Dynamic Characteristics

·	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		43.3		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		13.9		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		0.87		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		840		
Q_{gs}	Gate – Source Charge	$V_{\text{Bus}} = 100V$		318		пC
$Q_{gd} \\$	Gate – Drain Charge	$I_D = 580A$		402		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		32		
T_{r}	Rise Time	$\begin{split} V_{GS} &= 15 V \\ V_{Bus} &= 133 V \\ I_D &= 580 A \\ R_G &= 0.8 \Omega \end{split}$		64		na
$T_{d(off)}$	Turn-off Delay Time			88		ns
T_{f}	Fall Time			116		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$, $V_{Bus} = 133V$ $I_D = 580A$, $R_G = 0.8\Omega$		5		T
E_{off}	Turn-off Switching Energy			5.6		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		5.6		
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 133V$ $I_D = 580A, R_G = 0.8\Omega$		5.9		mJ

Source - Drain diode ratings and characteristics

Source Drain Grove racings and characteristics							
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_S	Continuous Source current		$Tc = 25^{\circ}C$			580	Α
	(Body diode)		$Tc = 80^{\circ}C$			434	А
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -580A$				1.3	V
dv/dt	Peak Diode Recovery •					8	V/ns
t _{rr}	Reverse Recovery Time	* 500 h	$T_j = 25^{\circ}C$			230	ns
	Transfer recovery Time	$I_S = -580A$ $V_R = 500V$	$T_j = 125$ °C			450	115
Q _{rr}	Reverse Recovery Charge	$di_{S}/dt = 600A/\mu s$	$T_j = 25^{\circ}C$		5.4		μС
	reverse receivery charge		$T_j = 125$ °C		20.4		μΟ

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

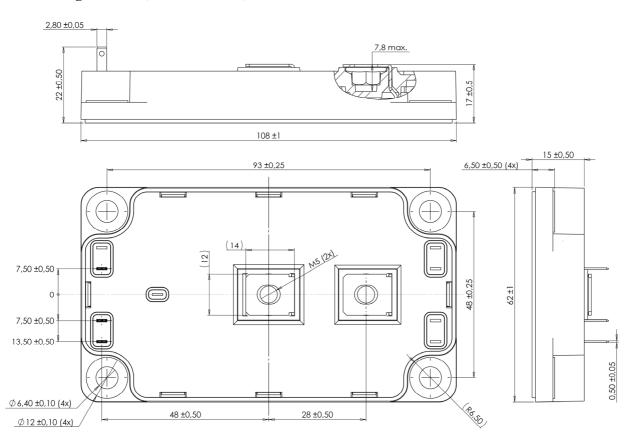
 $I_S \leq \text{-} \; 580 A \qquad di/dt \leq 700 A/\mu s \qquad V_R \leq V_{DSS} \qquad T_j \leq 150 ^{\circ} C$



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance					0.055	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150		
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Torque		For terminals	M5	2		3.5	11.111
Wt	Package Weight	·				300	g

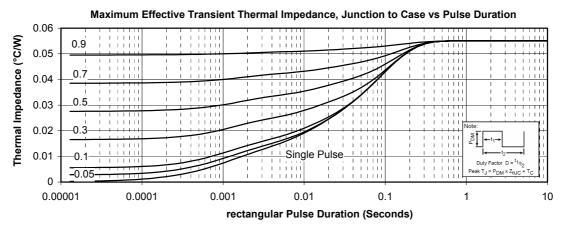
SP6 Package outline (dimensions in mm)

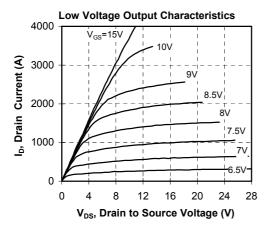


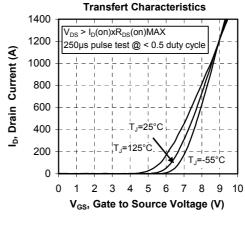
 $See \ application \ note \ APT0601 \ - \ Mounting \ Instructions \ for \ SP6 \ Power \ Modules \ on \ www.microsemi.com$

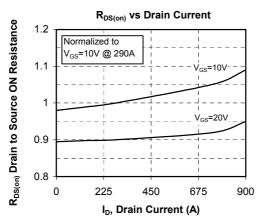


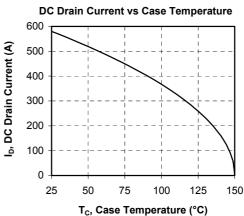
Typical Performance Curve



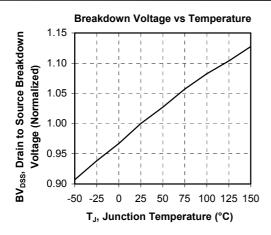


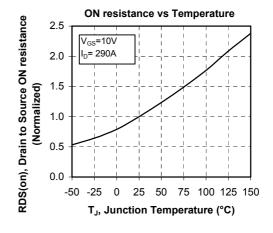


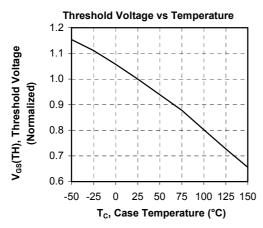


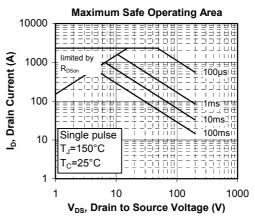


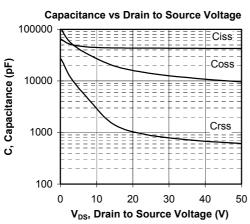


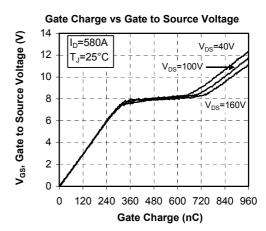




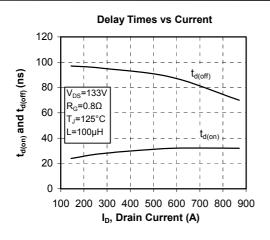


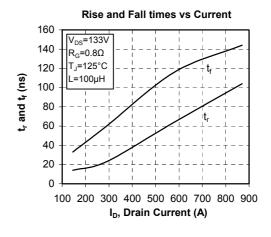


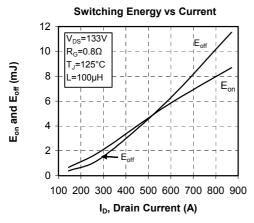


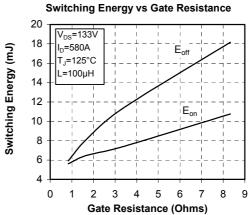


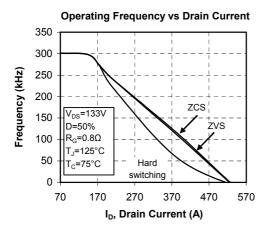


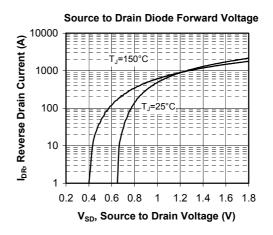












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